BRIGHTEK

BRIGHTEK (EUROPE) LIMITED

Brighten Up The World With LED!

ISO/TS 16949:2009 BS EN ISO 14001:2004 QC 080000 IECQ HSPM

PRODUCT DATASHEET

- ▶ DC Input Photo Coupler
- ▶ DIP6 Gullwing 400mil
- ▶ Zero-Cross TRIAC

Release Date: 10 June 2025 Version: A00

TD304X(M)-GV

TD304X(M) Series

TD304X(M) Series

RoHS Compliant

DESCRIPTION:

The TD304X(M) series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a monolithic silicon zero-cross photo TRIAC in a plastic DIP6 package with Gullwing lead forming option.

FEATURES:

- High isolation 5000Vrms
- DC input with zero-cross photo TRIAC output
- Operating temperature range -40°C to +100°C
- REACH & RoHS compliance
- MSL class 1
- Regulatory Approvals:
  - UL - UL1577
  - VDE - EN60747-5-5 (VDE0884-5)
  - CQC - GB4943.1, GB8898
- Packing: 65pcs/tube

APPLICATIONS:

- Solenoid/valve controls
- Lighting controls
- Motor controls
- Temperature controls
- Static AC power switches
- Solid state relays
- Interfacing microprocessors to 115 to 240VAC peripherals

Partner with: LIGHTNING

NAMING & ORDERING INFORMATION:

Naming Information:

TD304 X (M) - G V	
TD304	Part Number
X	Selection: LED Trigger Current (X=1~3)
M	Lead Form Option: DIP6 Gullwing
G	Green Option
V	VDE Option

Ordering Information:

TD304X(M)-GV

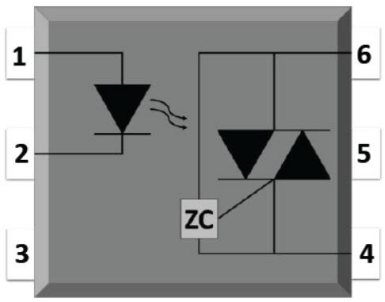
X = Selection: LED Trigger Current (X=1~3)

Part Number	Symbol	Values			Unit	Test Condition
		Min.	Typ.	Max.		
TD3041(M)-GV	I_{FT}	---	---	15	mA	I_{TM}=100mA Terminal Voltage=3V
TD3042(M)-GV		---	---	10		
TD3043(M)-GV		---	---	5		

Version No.	Original Release Date
Rev: A00	05/09/2024

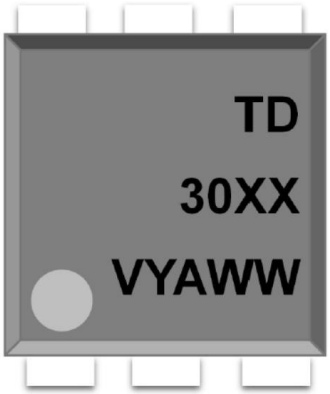
SCHEMATIC DIAGRAM & MARKING:

Schematic Diagram:



PIN Definition	
1	Anode
2	Cathode
3	NC
4	Terminal
5	Substrate
6	Terminal

Marking Information:



Marking Definition	
TD	Manufacturer Code
304X	Part Number & Rank
V	VDE Applicable
Y	Fiscal Year
A	Manufacturing Code
WW	Work Week

Labelling Information:

This product is manufactured, tested, and packed by

LIGHTNING

for more details, please visit www.tdled.com

ABSOLUTE CHARACTERISTICS:

Absolute Maximum Ratings:

Parameter	Symbol	Ratings	Unit
INPUT			
Forward Current	I_F	60	mA
Reverse Voltage	V_R	6	V
Junction Temperature	T_j	125	°C
Input Power Dissipation	P_I	100	mW
OUTPUT			
Off-State Output Terminal Voltage	V_{DRM}	400	V
Peak Repetitive Surge Current PW=100μs, 120pps	I_{TSM}	1	A
On-State RMS Current	$I_{T(RMS)}$	100	mA
Junction Temperature	T_j	125	°C
Output Power Dissipation	P_O	300	mW
COMMON			
Total Power Dissipation	P_{tot}	400	mW
Isolation Voltage	V_{iso}	5000 *1	Vrms
Operating Temperature	T_{opr}	-40~+100	°C
Storage Temperature	T_{stg}	-55~+125	°C
Soldering Temperature	T_{sol}	260 *2	°C

*1. AC for 1 minute, R.H.=40~60%.
*2. For 10 seconds max.

ELECTRICAL CHARACTERISTICS:

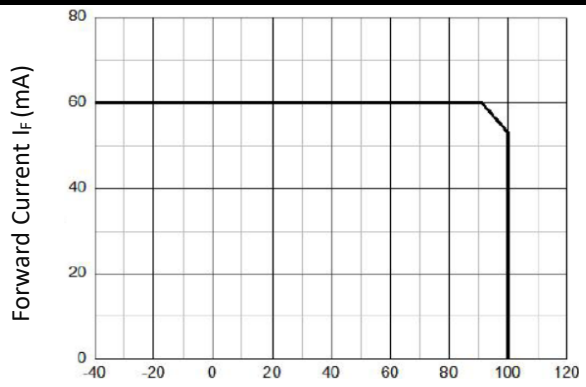
Electrical Optical Characteristics at T_a=25°C:

Parameter		Symbol	Values			Unit	Test Condition
			Min.	Typ.	Max.		
INPUT							
Forward Voltage		V_F	---	1.24	1.4	V	I_F=10mA
Reverse Current		I_R	---	---	10	μA	V_R=6V
Input Capacitance		C_{IN}	---	8.5	250	pF	V=0, f=1kHz
OUTPUT							
Peak Off-State Current Either Direction		I_{DRM}	---	---	500 *1	nA	V_{DRM}=Rated V_{DRM} I_F=0
Peak Off-State Voltage Either Direction		V_{TM}	---	1.59	2.5	V	I_{TM}=100mA
Critical Rate of Rise of Off-State Voltage		dV/dt	1000	---	---	V/μs	V_{PEAK}=400V I_F =0
TRANSFER CHARACTERISTICS							
LED Trigger Current	TD3041	I_{FT}	---	---	15	mA	I_{TM}=100mA Terminal Voltage=3V
	TD3042		---	---	10		
	TD3043		---	---	5		
Holding Current		I_H	---	237	---	μA	---
Isolation Resistance		R_{ISO}	10^12	10^14	---	Ω	DC=500V, 40~60% R.H.
Floating Capacitance		C_{IO}	---	0.4	---	pF	V=0, f=1MHz
ZERO-CROSSING CHARACTERISTICS							
Inhibit Voltage		V_{INH}	---	---	20	V	I_F=Rated I_{FT}
Leakage in Inhibited State		I_{DRM2}	---	---	500	μA	I_F=Rated I_{FT} V_{DRM}=Rated V_{DRM}

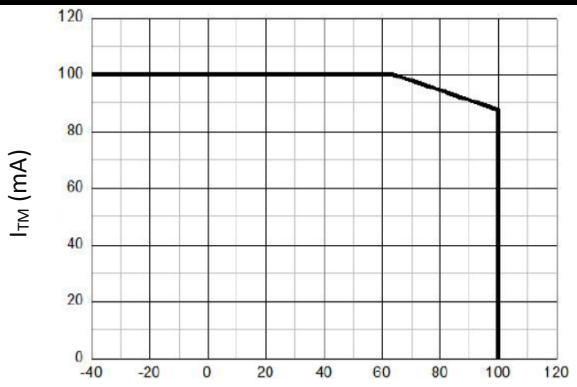
*1. Test voltage must be applied within dV/dt rating.

CHARACTERISTIC CURVES:

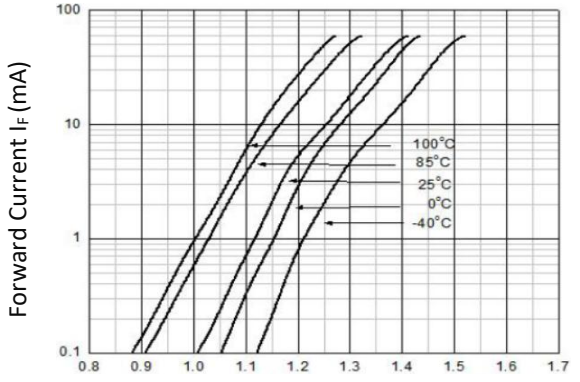
Forward Current v.s. Ambient Temperature



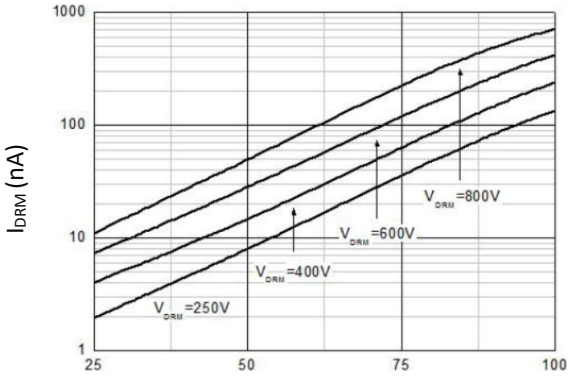
On-State Terminal Current v.s. Ambient Temp.



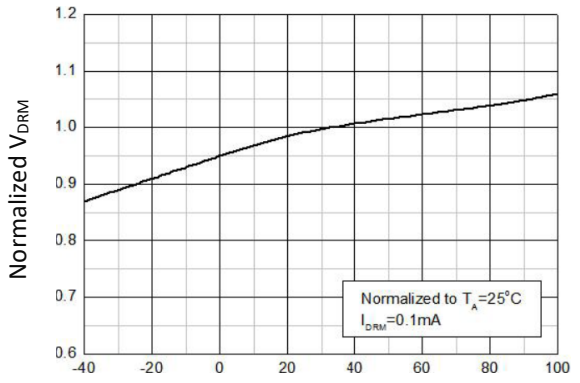
Forward Current v.s. Forward Voltage



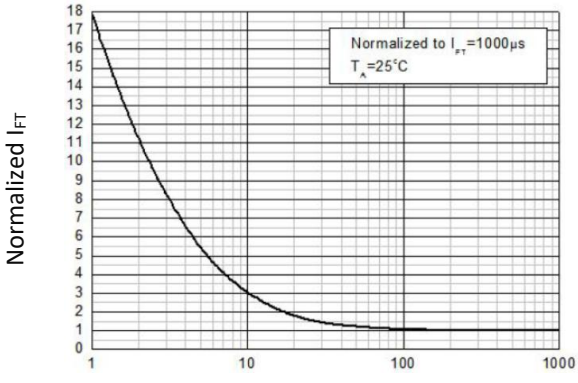
Off-State Terminal Current v.s. Ambient Temperature



Normalized Off-State Terminal Voltage v.s. Ambient Temperature

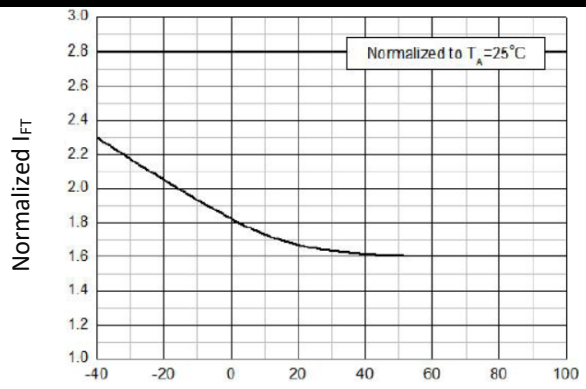


Normalized Trigger Current v.s. LED Trigger Pulse Width

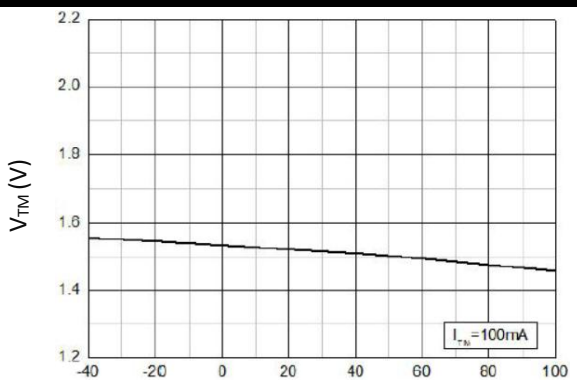


CHARACTERISTIC CURVES:

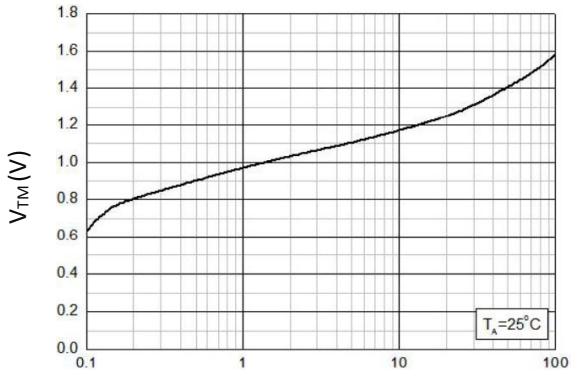
Normalized Trigger Current v.s. Ambient Temperature



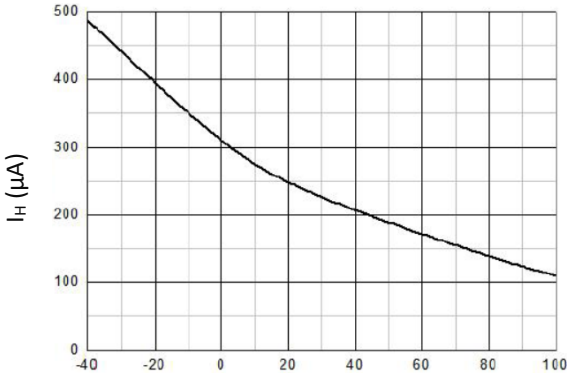
On-State Terminal Voltage v.s. Ambient Temperature



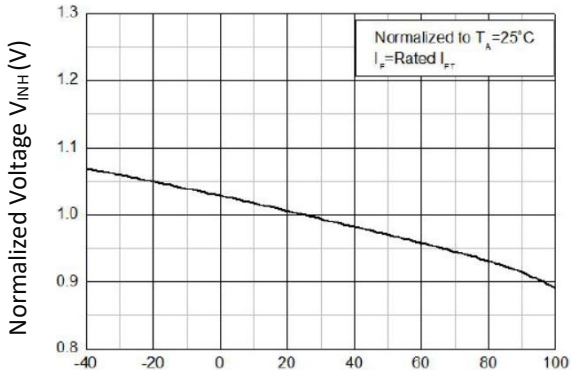
On-State Terminal Voltage v.s. On-State Terminal Current



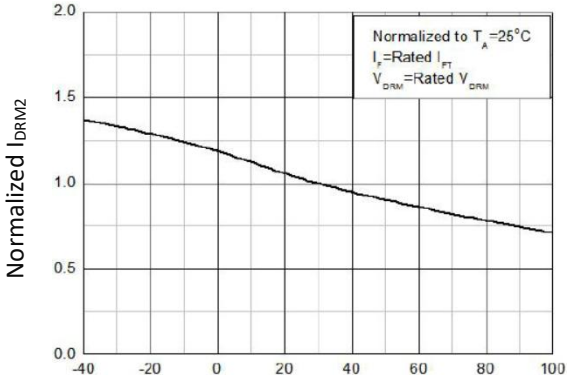
Holding Current v.s. Ambient Temperature



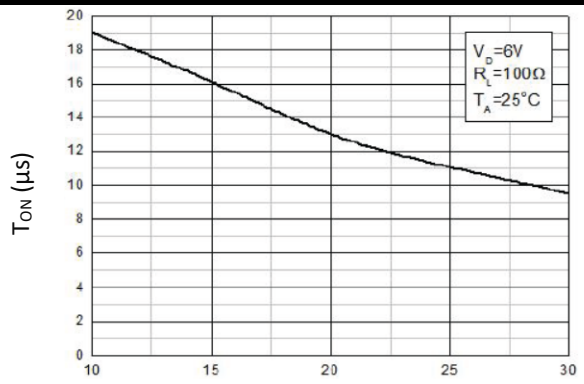
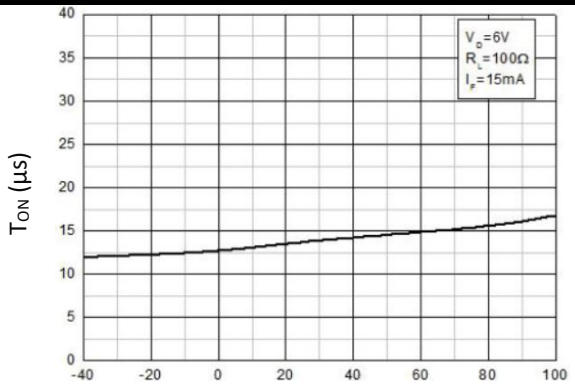
Normalized Inhibit Voltage v.s. Ambient Temperature



Normalized Leakage in Inhibit State v.s. Ambient Temperature

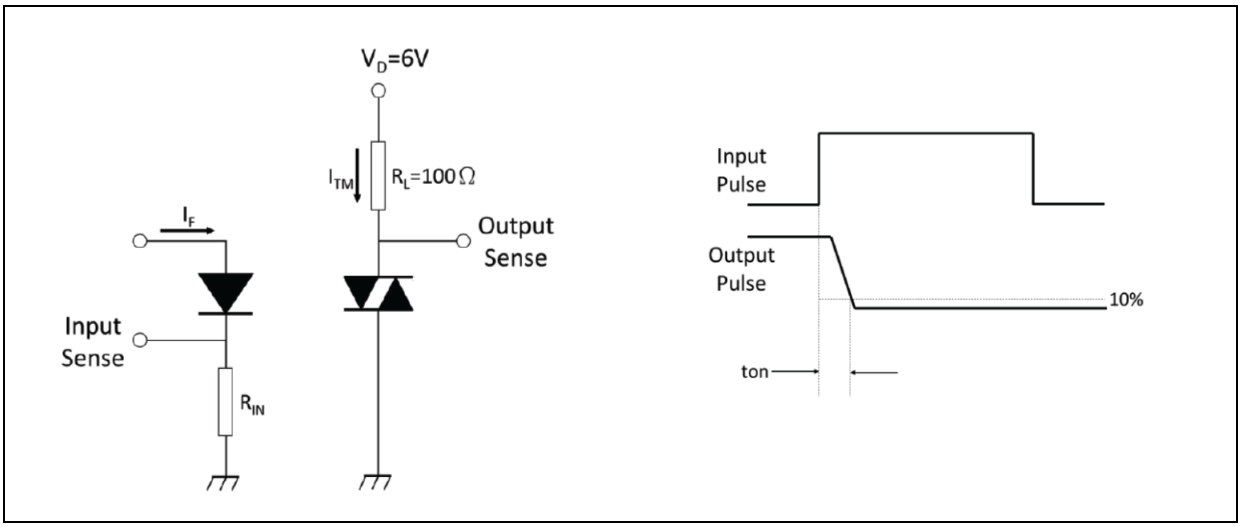


CHARACTERISTIC CURVES:

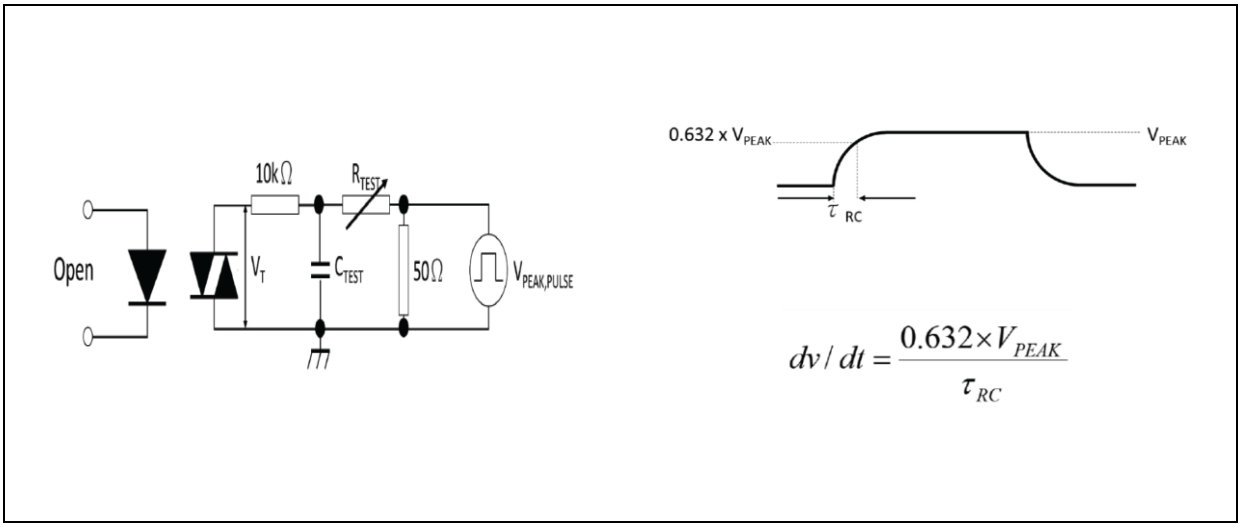
Turn On Time v.s. Forward Current	Turn On Time v.s. Ambient Temperature
	

TEST CIRCUIT:

Test Circuit and Waveforms of Turn On Time:



Test Circuit and Waveforms of dV/dt:

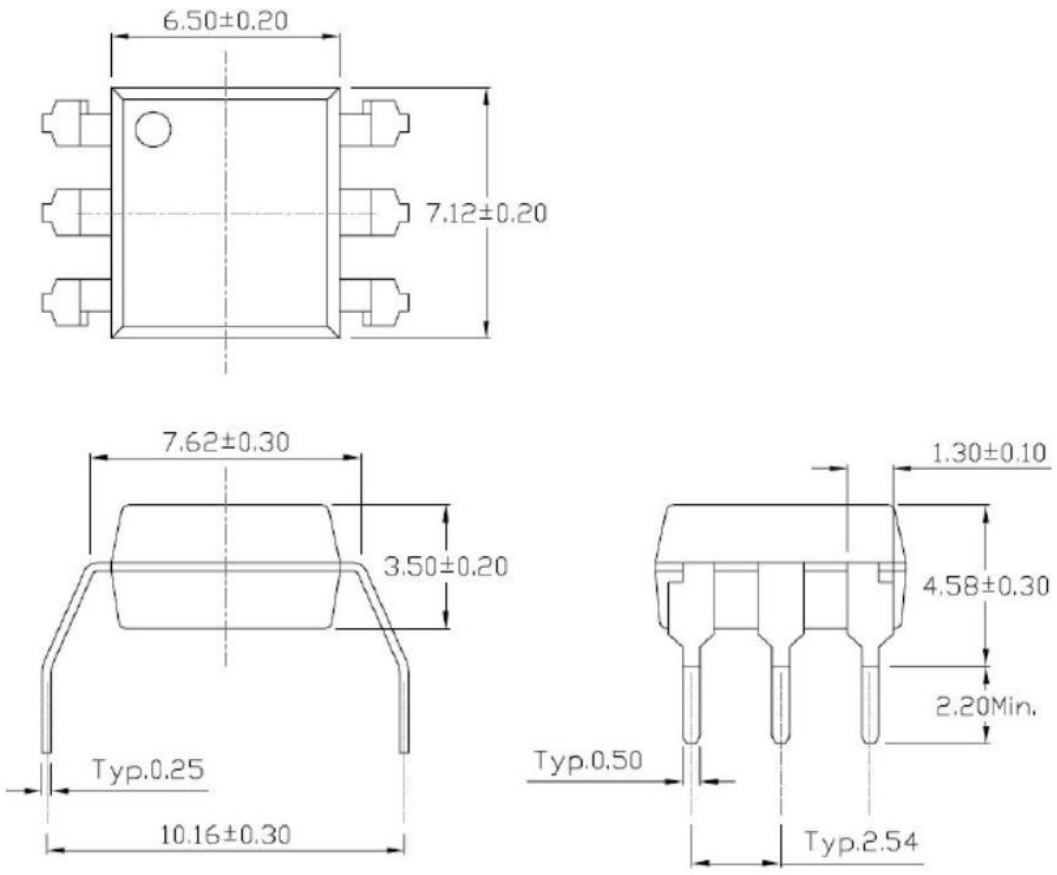


$$dv/dt = \frac{0.632 \times V_{PEAK}}{\tau_{RC}}$$

OUTLINE DIMENSION:

Package Dimension:

Gullwing (400mil) Lead Forming - Through Hole (M Type)

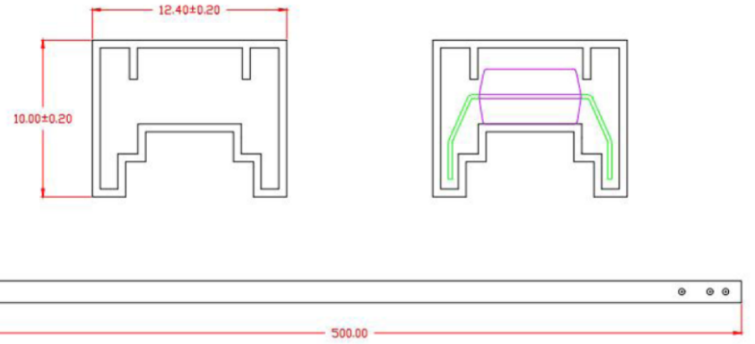


1. All dimensions are in millimetre (mm).

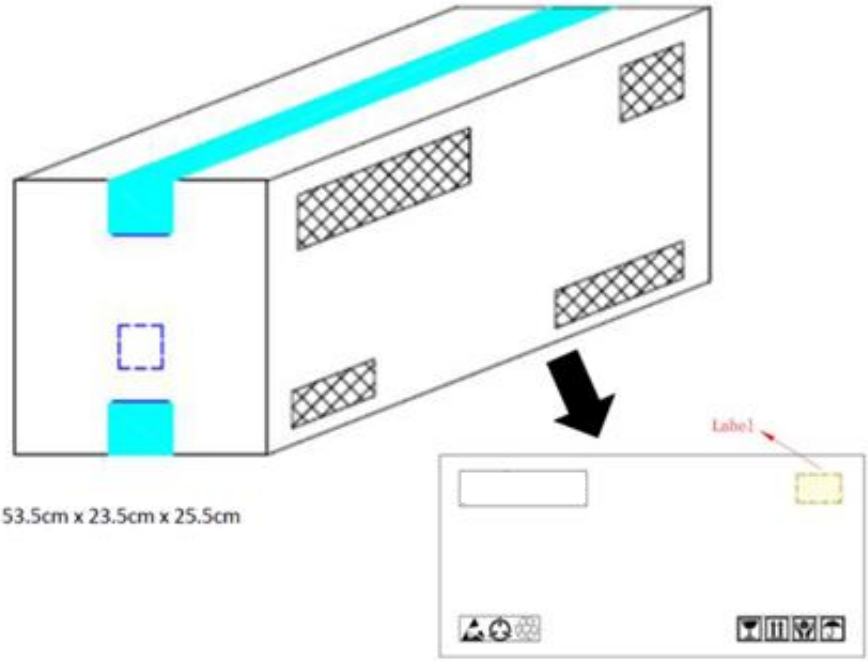
PACKING SPECIFICATION:

Tube Dimension:

65pcs/tube, 32 tube/inner box, 10 inner box (20.8Kpcs)/carton



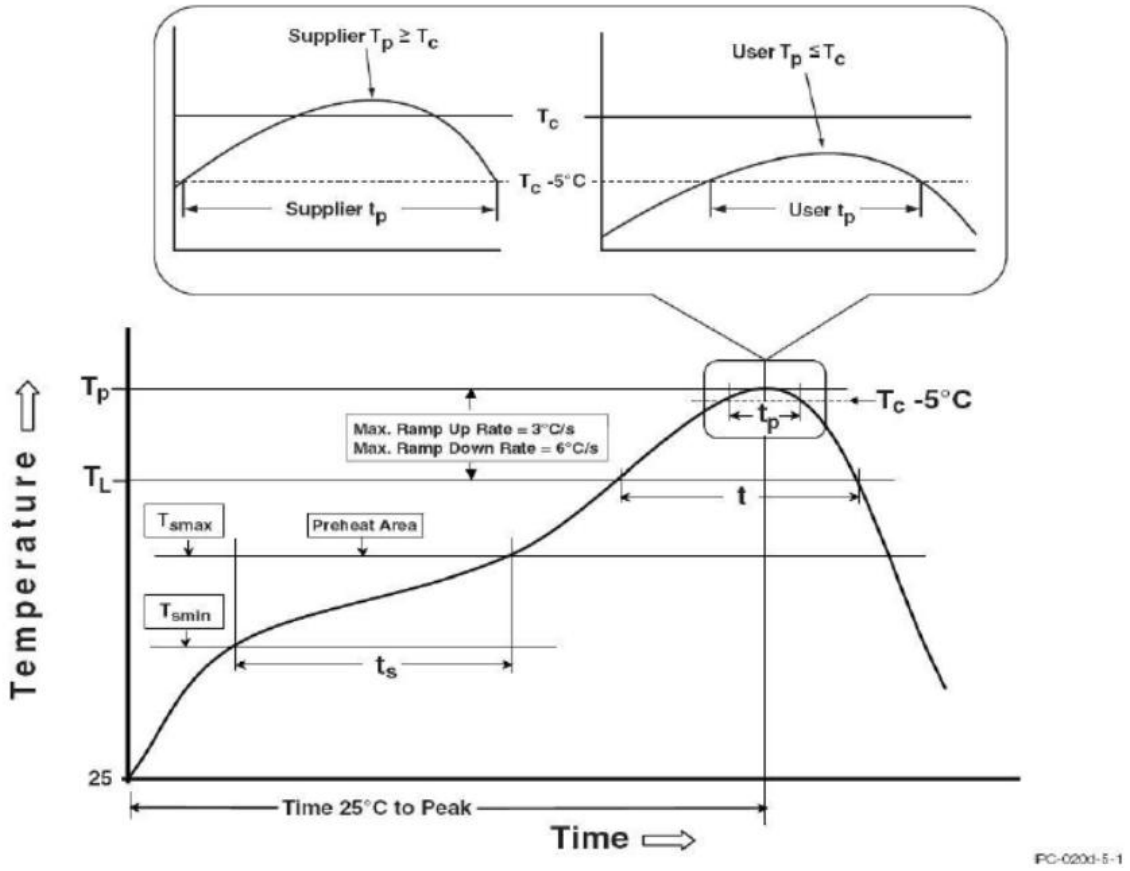
- L x W x H = 52.5cm x 10.7cm x 4.7cm



- L x W x H = 53.5cm x 23.5cm x 25.5cm

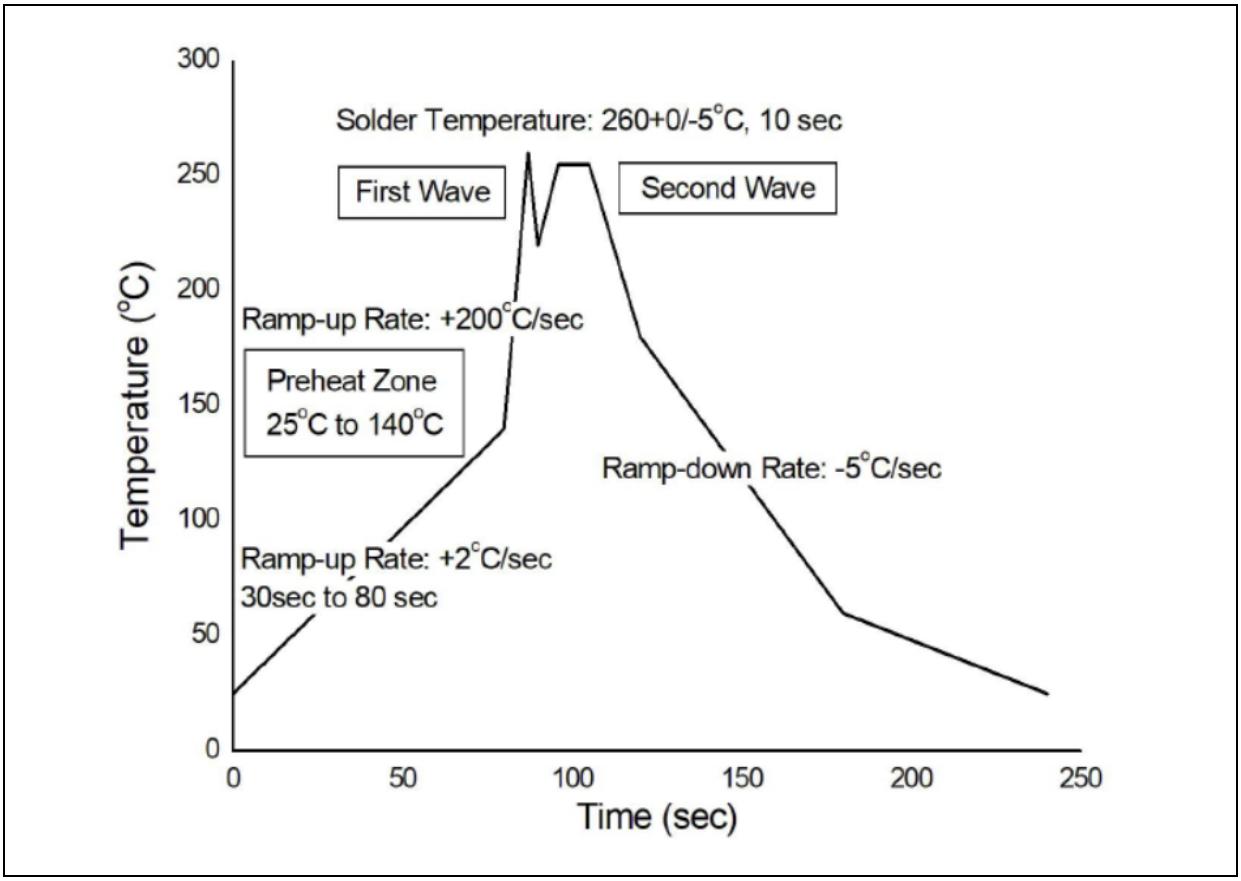
RECOMMENDED SOLDERING PROFILE:

Reflow Information:



Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (T_{smin})	100°C	150°C
Temperature Max. (T_{smax})	150°C	200°C
Time (t_s) from (T_{smin} to T_{smax})	60-120 seconds	60-120 seconds
Ramp-up Rate (t_L to t_P)	3°C/second max.	3°C/second max.
Liquidous Temperature (T_L)	183°C	217°C
Time (t_L) Maintained Above (T_L)	60-150 seconds	60-150 seconds
Peak Body Package Temperature	235°C +0°C / -5°C	260°C +0°C / -5°C
Time (t_P) within 5°C of 260°C	20 seconds	30 seconds
Ramp-down Rate (T_P to T_L)	6°C/second max.	6°C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

Wave Soldering (JESD22-A111 Compliant):



Hand Soldering:

Soldering Temperature	380±5°C
Soldering Time	3 sec max.

Note:

- One time soldering is recommended for all soldering methods.
- Do not solder more than three times for IR reflow soldering.